

ADD-A-PAK Gen 7 Power Modules Schottky Rectifier, 200 A



PRODUCT SUMMARY				
I _{F(AV)}	200 A			
V _R	100 V			
Package	ADD-A-PAK Gen 7			
Circuit	Two diodes common anode			

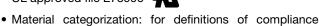
MECHANICAL DESCRIPTION

The ADD-A-PAK Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- 175 °C T_J operation
- · Low forward voltage drop
- High frequency operation
- · Low thermal resistance
- UL approved file E78996





please see www.vishay.com/doc?99912 · Designed and qualified for industrial level

BENEFITS

- · Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- · Easy mounting on heatsink

ELECTRICAL DESCRIPTION

The VS-VSKJS203.. Schottky rectifier common anode has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	200	Α		
V _{RRM}		100	V		
I _{FSM}	t _p = 5 μs sine	12 800	Α		
V _F	100 A _{pk} , T _J = 125 °C	0.87	V		
T _J	Range	-55 to +175	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-VSKJS203/100	UNITS		
Maximum DC reverse voltage	V_{R}	100	V		
Maximum working peak reverse voltage	V_{RWM}	100	V		



ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average	per module	I _{F(AV)} 50 % duty cycle at T _C = 121 °C, rectangular waveform			200	
forward current	per leg	g I _{F(AV)}	30 % duty cycle at 1 _C = 121 G, rectangular wavelonn		100	
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	12 800	Α	
non-repetitive surge current		I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	1700	
Non-repetitive avalanche energ	Jy	E _{AS}	T _J = 25 °C, I _{AS} = 5.5 A, L = 1 mH		15	mJ
Repetitive avalanche current		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		А	

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V _{FM}	100 A	T _J = 25 °C	0.99	V
		200 A		1.34	
		100 A	T _J = 125 °C	0.87	
		200 A		1.09	
Maximum reverse leakage current	I _{RM}	T _J = 25 °C	V _R = Rated V _R	3	mΛ
Maximum reverse leakage current		T _J = 125 °C		65	mA
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		2750	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		7.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs
Maximum RMS insulation voltage	V _{INS}	50 Hz		3000 (1 min) 3600 (1 s)	V

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range)	T _J , T _{Stg}		-55 to +175	°C
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	0.52	°C/W
Typical thermal resistance, case to heatsink per module		R _{thCS}		0.1	C/VV
Approximate weight				75	g
Approximate weight				2.7	oz.
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the	4	Nm
	busbar		spread of the compound.	3	INIII
Case style			JEDEC®	TO-240AA co	mpatible

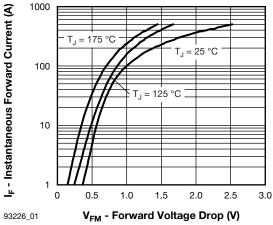


Fig. 1 - Maximum Forward Voltage Drop Characteristics

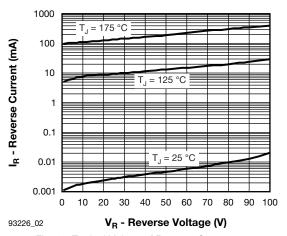


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

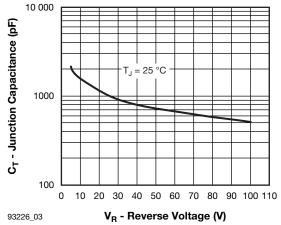


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

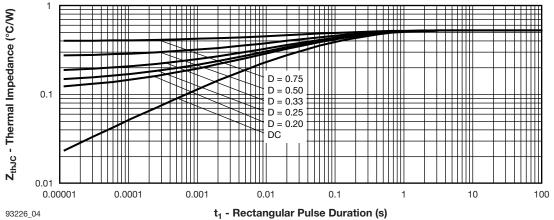


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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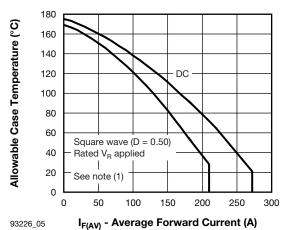


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

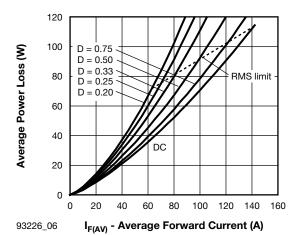


Fig. 6 - Forward Power Loss Characteristics

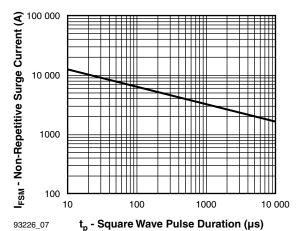


Fig. 7 - Maximum Non-Repetitive Surge Current

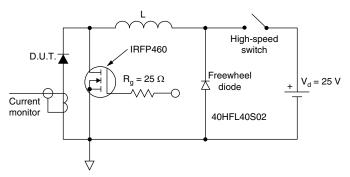


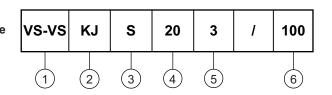
Fig. 8 - Unclamped Inductive Test Circuit

Note

Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; Pd = Forward power loss = $I_{F(AV)}$ x V_{FM} at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_{R} (1 - D)$; I_{R} at V_{R1} = 80 % rated V_{R}

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Circuit configuration:

KJ = ADD-A-PAK - 2 diodes/common anode

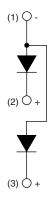
3 - S = Schottky diode

4 - Average current rating (20 = 200 A)

5 - Product silicon identification

6 - Voltage rating (100 = 100 V)

CIRCUIT CONFIGURATION

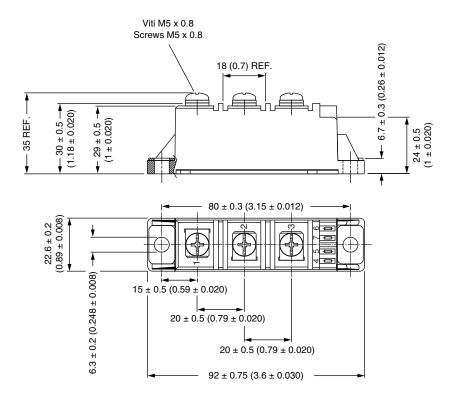


LINKS TO RELATED DOCUMENTS				
Dimensions www.vishav.com/doc?95369				



ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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